NSN 5962-01-101-7555

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-101-7555 **Body Length:** 0.896 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Operating Tempurature Range:** -0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Low power and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.3 volts power source **Time Rating Per Chacteristic:** 45.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 16331-63a133590 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

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Demilitarization: Yes - demil/mli